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Layered Structures and Epitaxy

Editors: J. M. Gibson, G. C. Osbourn and R. M. Tromp

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Preface

This book contains written accounts of almost all papers presented during the Symposium on Layered Structures and Epitaxy, held during the Meeting of the Materials Research Society in Boston, December, 1-6, 1985. The Symposium covered new developments in epitaxial growth, superlattices, quantum wells and (amorphous) layered systems. The organizers thank all authors for their invaluable contributions which made this symposium a successful enterprise.

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